



RELIABILITY REPORT  
FOR MAX9666ETP+  
PLASTIC ENCAPSULATED DEVICES

October 30, 2009

**MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR.  
SUNNYVALE, CA 94086

<b>Approved by</b>
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## Conclusion

The MAX9666ETP+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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### I. Device Description

#### A. General

The MAX9665/MAX9666/MAX9667 provide multiple programmable reference voltages for gamma correction in TFT LCDs and a programmable reference voltage for VCOM adjustment. All gamma and VCOM reference voltages, have a 10-bit digital-to-analog converter (DAC), and buffer with high peak current. This reduces the recovery time of the output voltages voltage when critical levels and patterns are displayed. These devices include multiple-time programmable (MTP) memory to store gamma and VCOM codes on the chip, eliminating the need for external EEPROM. The MTP memory supports up to 100 write operations. The MAX9665/MAX9666/MAX9667 feature an I2C interface to control the programmable reference voltages and a single-wire interface to toggle the VCOM reference voltage up or down.

## II. Manufacturing Information

A. Description/Function:	6/8/10-Channel, 10-Bit, Nonvolatile Programmable Gamma and VCOM Reference Voltages
B. Process:	S45
C. Number of Device Transistors:	39620
D. Fabrication Location:	California, Texas or Japan
E. Assembly Location:	China, Thailand
F. Date of Initial Production:	October 22, 2009

## III. Packaging Information

A. Package Type:	20-pin TQFN 5x5
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-3746
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	48°C/W
K. Single Layer Theta Jc:	2.1°C/W
L. Multi Layer Theta Ja:	32°C/W
M. Multi Layer Theta Jc:	2.7°C/W

## IV. Die Information

A. Dimensions:	88 X 98 mils
B. Passivation:	Si <sub>3</sub> N <sub>4</sub> /SiO <sub>2</sub> (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn)
F. Minimum Metal Spacing:	Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO <sub>2</sub>
I. Die Separation Method:	Wafer Saw

## V. Quality Assurance Information

A. Quality Assurance Contacts:	Ken Wendel (Director, Reliability Engineering) Bryan Preeshl (Managing Director of QA)
B. Outgoing Inspection Level:	0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
C. Observed Outgoing Defect Rate:	< 50 ppm
D. Sampling Plan:	Mil-Std-105D

## VI. Reliability Evaluation

### A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 48 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 22.9 \times 10^{-9}$$
$$\lambda = 22.9 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maxim-ic.com/qa/reliability/monitor>. Cumulative monitor data for the S45 Process results in a FIT Rate of 0.49 @ 25C and 8.49 @ 55C (0.8 eV, 60% UCL)

### B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

### C. E.S.D. and Latch-Up Testing

The DV22 die type has been found to have all pins able to withstand a transient pulse of:

HBM:	+/-2500V per JEDEC JESD22-A114
MM:	+/-200V per JEDEC JESD22-A115

Latch-Up testing has shown that this device withstands a current of +/- 200mA and Vcc Overvoltage per JESD78, except the SCL pin which passes +/-100mA.

**Table 1**  
Reliability Evaluation Test Results

**MAX9666ETP+**

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES
<b>Static Life Test</b> (Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	48	0
<b>Moisture Testing</b> (Note 2)				
HAST	Ta = 130°C RH = 85% Biased Time = 96hrs.	DC Parameters & functionality	77	0
<b>Mechanical Stress</b> (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality	77	0

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data